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Configurable Multifunction Gate

The NL7SZ98 is an advanced high-speed CMOS multifunction gate. The device allows the user to choose logic functions MUX, AND, OR, NAND, NOR, INVERT and BUFFER. The device has Schmitt-trigger inputs, thereby enhancing noise immunity.

The NL7SZ98 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

Features

- High Speed: $t_{PD} = 3.4 \text{ ns (Typ)} @ V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation: $I_{CC} = 1 \mu A$ (Maximum) at $T_A = 25^{\circ}C$
- Power Down Protection Provided on inputs
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Package
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- This is a Pb-Free Device



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SC-88 (SOT-363) CASE 419B

MARKING DIAGRAM



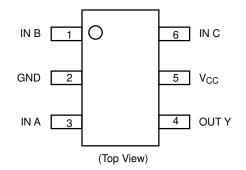
MP = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

PIN ASSIGNMENTS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

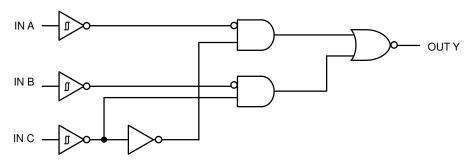


Figure 1. Function Diagram

PIN ASSIGNMENT

1	IN B
2	GND
3	IN A
4	OUT Y
5	V _{CC}
6	IN C

FUNCTION TABLE*

	Input					
Α	В	С	Υ			
L	L	L	Н			
L	L	Н	Н			
L	Н	L	L			
L	Н	Н	Н			
Н	L	L	Н			
Н	L	Н	L			
Н	Н	L	L			
Н	Н	Н	Ĺ			

^{*}To select a logic function, please refer to "Logic Configurations section".

LOGIC CONFIGURATIONS

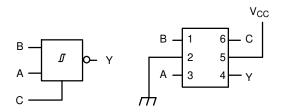


Figure 2. 2–Input MUX with Output Inverted

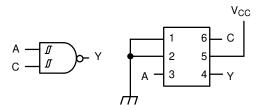


Figure 3. 2-Input NAND (When B = "L")

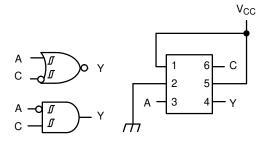


Figure 4. 2-Input NOR with Input C Inverted (When B = "H")

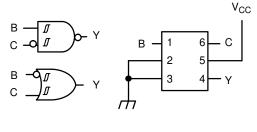


Figure 5. 2-Input NAND with Input C Inverted (When A = "L")

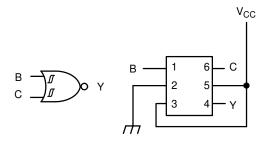


Figure 6. 2-Input NOR (When A ="H")

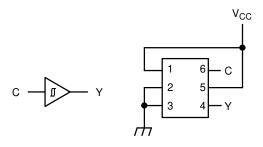


Figure 7. Buffer (When A = "L" and B = "H")

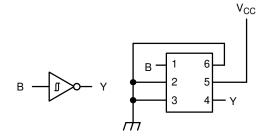


Figure 8. Inverter (When A = C = "L")

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
V _{IN}	DC Input Voltage		-0.5 to +7.0	V
V _{OUT}	DC Output Voltage		-0.5 to +7.0	V
I _{IK}	DC Input Diode Current	V _{IN} < GND	-50	mA
I _{OK}	DC Output Diode Current	V _{OUT} < GND	-50	mA
Io	DC Output Source/Sink Current	±50	mA	
I _{CC}	DC Supply Current Per Supply Pin	±100	mA	
I _{GND}	DC Ground Current per Ground Pin	±100	mA	
T _{STG}	Storage Temperature Range	−65 to +150	°C	
TL	Lead Temperature, 1 mm from Case for 10 S	econds	260	°C
TJ	Junction Temperature Under Bias		+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 1)	SC-88	350	°C/W
P _D	Power Dissipation in Still Air at 85°C	SC-88	200	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating Oxygen	Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	_	uman Body Mode (Note 2) Machine Model (Note 3) ged Device Model (Note 4)	>2000 >200 N/A	V
I _{LATCHUP}	Latchup Performance Above $V_{\mbox{\footnotesize CC}}$ and Below	GND at 125°C (Note 5)	±500	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.
- 2. Tested to EIA/JESD22-A114-A.
- 3. Tested to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.
- 5. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V _{CC}	Positive DC Supply Voltage	1.65	5.5	V	
V _{IN}	Digital Input Voltage	0	5.5	V	
V _{OUT}	Output Voltage	0	5.5	V	
T _A	Operating Free-Air Temperature		-55	+125	°C
Δt/ΔV	1 '	$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0 0	No Limit No Limit No Limit	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

			V _{CC}	-	Γ _A = 25°0	С	T _A ≤	+85°C	T _A = -55°C to +125°C			
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit	
V_{T+}	V _{T+} Positive Threshold Voltage		1.65	0.79		1.16		1.16		1.16	V	
		Voltage		2.3	1.11		1.56		1.56		1.56	
			3.0	1.5		1.87		1.87		1.87		
			4.5	2.16		2.74		2.74		2.74		
			5.5	2.61		3.33		3.33		3.33		
V_{T-}	Negative		1.65	0.35		0.62	0.35		0.35		V	
	Threshold Voltage		2.3	0.58		0.87	0.58		0.58			
			3.0	0.84		1.19	0.84		0.84			
			4.5	1.41		1.9	1.41		1.41			
			5.5	1.78		2.29	1.78		1.78			
V _H	Hysteresis Voltage		1.65	0.30		0.62	0.30	0.62	0.30	0.62	V	
			2.3	0.40		0.8	0.40	0.8	0.40	0.8		
			3.0	0.53		0.87	0.53	0.87	0.53	0.87		
			4.5	0.71		1.04	0.71	1.04	0.71	1.04		
			5.5	0.8		1.2	0.8	1.2	0.8	1.2		
V _{OH}	Minimum High-Level Output	$V_{IN} \leq V_{T-MIN}$ $I_{OH} = -50 \mu A$	1.65 – 5.5	V _{CC} - 0.1			V _{CC} - 0.1		V _{CC} - 0.1		V	
	Voltage	$V_{IN} \leq V_{T-MIN}$										
		I _{OH} = -4 mA	1.65	1.2			1.2		1.2			
		I _{OH} = -8 mA	2.3	1.9			1.9		1.9			
		I _{OH} = -16 mA	3.0	2.4			2.4		2.4			
		I _{OH} = -24 mA	3.0	2.3			2.3		2.3			
		I _{OH} = -32 mA	4.5	3.8			3.8		3.8			
V _{OL}	Maximum Low-Level Output	$V_{IN} \ge V_{T+MAX}$ $I_{OL} = 50 \mu A$	1.65 – 5.5			0.1		0.1		0.1	V	
	Voltage	$V_{IN} \geq V_{T+MAX}$										
		I _{OL} = 4 mA	1.65			0.45		0.45		0.45		
		I _{OL} = 8 mA	2.3			0.3		0.3		0.3		
		I _{OL} = 16 mA	3.0			0.4		0.4		0.4		
		I _{OL} = 24 mA	3.0			0.55		0.55		0.55		
		I _{OL} = 32 mA	4.5			0.55		0.55		0.55		
I _{IN}	Input Leakage Current	0 ≤ V _{IN} ≤ 5.5 V	0 to 5.5			±0.1		±1.0		±1.0	μΑ	
lcc	Quiescent Supply Current	$0 \le V_{IN} \le V_{CC}$	5.5			1.0		10		10	μΑ	

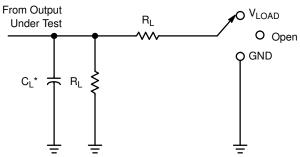
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

			$T_A = 25^{\circ}C$ $T_A \leq +85^{\circ}C$		T _A = 25°C		+85°C		-55°C 25°C		
Symbol	Parameter	V _{CC} (V)	Test Condition	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLH} ,	Propagation Delay,	1.65 – 1.95		3.2	8.9	14.4	3.2	14.4	3.2	14.4	ns
tPHL	Any Input to Output Y (See Test Circuit)	2.3 – 2.7		2.0	5.2	8.3	2.0	8.3	2.0	8.3	
		3.0 – 3.6		1.5	4.0	6.3	1.5	6.3	1.5	6.3	
		4.5 – 5.5		1.1	3.4	5.1	1.1	5.1	1.1	5.1	
C _{IN}	Input Capacitance				3.5						pF
C _{PD}	Power Dissipation Capacitance (Note 6)	5.0	f = 10 MHz		22						pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TEST CIRCUIT AND VOLTAGE WAVEFORMS



Test	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V_{LOAD}
t _{PHZ} /t _{PZH}	GND

Figure 9. Load Circuit

	Inputs						
V _{CC}	VI	t _r /t _f	V _M	V_{LOAD}	C _L	R_{L}	V_{Δ}
1.8 V ± 0.15 V	V _{CC}	≤ 2 ns	V _{CC} /2	2 x V _{CC}	30 pF	1 kΩ	0.15 V
2.5 V ± 0.2 V	V _{CC}	≤ 2 ns	V _{CC} /2	2 x V _{CC}	30 pF	500 Ω	0.15 V
3.3 V ± 0.3 V	3 V	≤ 2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5.5 V ± 0.5 V	V _{CC}	≤ 2.5 ns	V _{CC} /2	2 x V _{CC}	50 pF	500 Ω	0.3 V

^{6.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption: P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

 $^{^{\}star}C_{L}$ includes probes and jig capacitance.

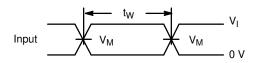


Figure 10. Voltage Waveforms Pulse Duration

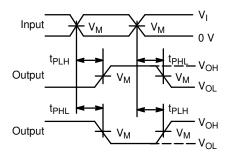


Figure 12. Voltage Waveforms Propagation Delay Times Inverting and Noninverting Outputs

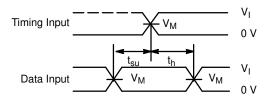


Figure 11. Voltage Waveforms Setup and Hold Times

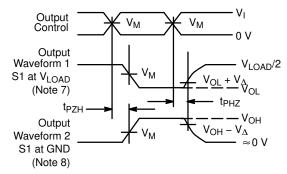


Figure 13. Voltage Waveforms Enable and Disable Times Low- and High-Level Enabling

- 7. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
- 8. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control
- 9. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_{\rm O} = 50 \ \Omega$.
- 10. The outputs are measured one at a time, with one transition per measurement.
- 11. All parameters are waveforms are not applicable to all devices.

ORDERING INFORMATION

Device	Package	Shipping [†]		
NL7SZ98DFT2G	SC-88	3000 / Tape & Reel		
NLV7SZ98DFT2G*	(Pb-Free)			

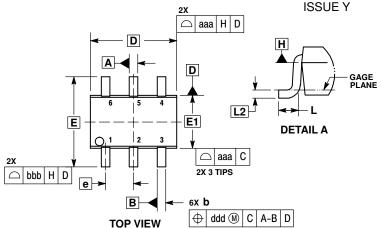
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

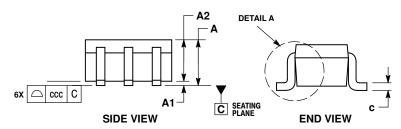
^{*}NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363

CASE 419B-02





NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- DIMENSIONING AND JUEENANCING FER ASME 114-3M, 1994
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,
 PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END.
 DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF
 THE PLASTIC BODY AND DATUM H.

- THE PLASTIC BOUT AIND ATOM IN.

 DATUMS A AND B ARE DETERMINED AT DATUM H.

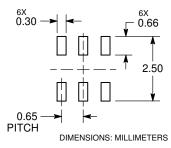
 DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE

 LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.

 DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION.
- ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION 6 AT MAXIMUM MATERIAL CONDI-TION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

	MIL	LIMETE	ERS	INCHES				
DIM	MIN	NOM	MAX	MIN	NOM	MAX		
Α			1.10			0.043		
A1	0.00		0.10	0.000		0.004		
A2	0.70	0.90	1.00	0.027	0.035	0.039		
b	0.15	0.20	0.25	0.006	0.008	0.010		
С	0.08	0.15	0.22	0.003	0.006	0.009		
D	1.80	2.00	2.20	0.070	0.078	0.086		
Е	2.00	2.10	2.20	0.078	0.082	0.086		
E1	1.15	1.25	1.35	0.045	0.049	0.053		
е		0.65 BS	С	0.026 BSC				
L	0.26	0.36	0.46	0.010	0.014	0.018		
L2		0.15 BS	C	0.006 BSC				
aaa	0.15			0.006				
bbb	0.30			0.012				
ccc		0.10		0.004				
ddd		0.10			0.004			

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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